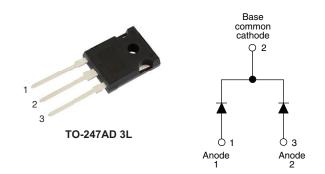
# VS-C4PH3006L-N3

**Vishay Semiconductors** 

### Hyperfast Soft Recovery Diode, 2 x 15 A FRED Pt® Gen 4



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PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 15 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.28 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

#### **FEATURES**

- Gen 4 FRED Pt<sup>®</sup> technology
- Low I<sub>BBM</sub> and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- 175 °C operating junction temperature
- Designed and gualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

Gen 4 Fred technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS				
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 142 °C	15	^				
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C$ = 25 °C, $t_p$ = 8.3 ms, half sine wave	200	A				
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS			MAX.	UNITS		
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
		I <sub>F</sub> = 15 A	-	1.6	1.9			
	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.87	-	V		
Forward voltage		I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C	-	1.35	-			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.67	-			
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.28	1.52			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.61	-			
	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	15			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	16	-	pF		



RoHS COMPLIANT HALOGEN FREE

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	+	T <sub>J</sub> = 25 °C		-	50	-	20	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	70	-	ns	
Peak recovery current		T <sub>J</sub> = 25 °C		-	8.5	-	A	
Feak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	16	-		
	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	250	-	20	
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	600	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1.4			
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	°C/W		
Thermal resistance, case to heat sink	R <sub>thCS</sub>		-	0.4	-			
Weight			-	6.0	-	g		
Weight			-	0.21	-	oz.		
Mounting torque			6.0 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	C4PH3006L					

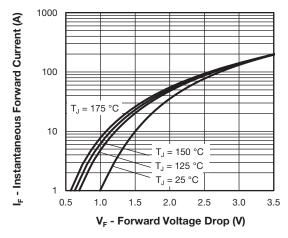


Fig. 1 - Typical Forward Voltage Drop Characteristics

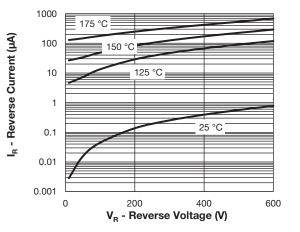


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



#### **Vishay Semiconductors**

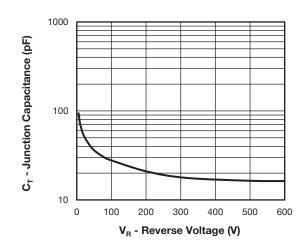


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

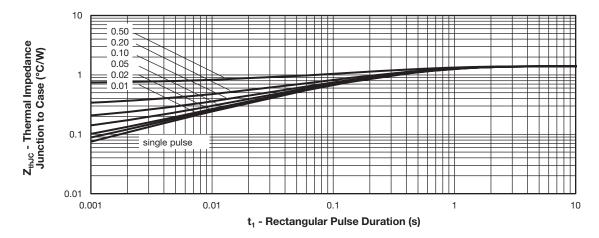
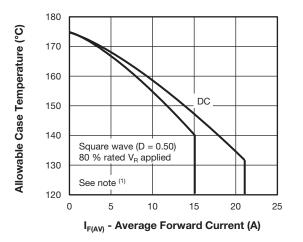
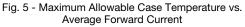


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V_{FM}} \ at \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{Fig.5}) \\ \mathsf{P}_{\mathsf{dREV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R}1} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ at \ \mathsf{V}_{\mathsf{R}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

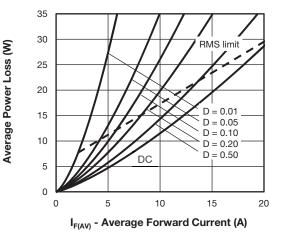


Fig. 6 - Forward Power Loss Characteristics

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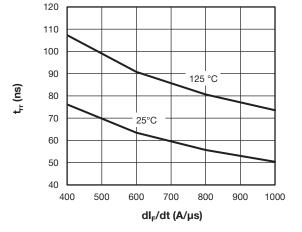


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

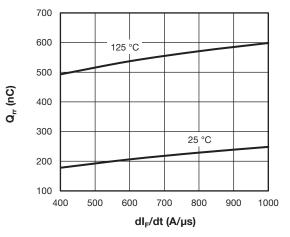


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

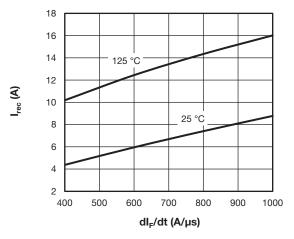


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

### Vishay Semiconductors



#### **ORDERING INFORMATION TABLE**

Device code	VS-	С	4	Р	Н	30	06	L	-N3
	1	2	3	4	5	6	7	8	9
	1 - Vishay Semiconductors product								
	2 -	Circ	uit conf	iguratior	1:				
		C =	commo	on catho	de				
	3 - FRED Pt Gen 4								
	4 - P = TO-247 package								
	5 -	Pro	cess typ	be:					
		H =	hyperfa	st recov	very				
	6 - Current rating (30 = 2 x 15 A)								
	7 - Voltage rating (06 = 600 V)								
	8 - Package: L = long lead								
	9 -			ital digit: en-free,		complia	nt, and	totally l	ead (Pb

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-C4PH3006L-N3	25	500	Antistatic plastic tube			

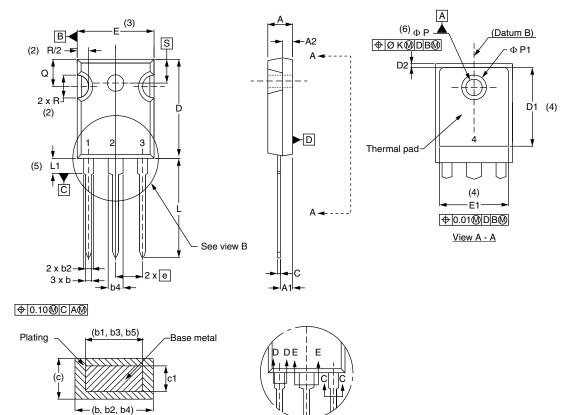
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95626					
Part marking information	www.vishay.com/doc?95007					



**Vishay Semiconductors** 

TO-247AD 3L

#### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INC	INCHES	
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- <sup>(3)</sup> Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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